

No.3773A

2SK1472**SANYO**

N-Channel MOS Silicon FET

Very High-Speed
Switching Applications**Features**

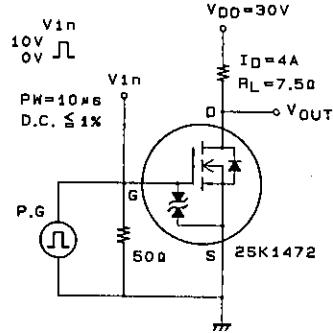
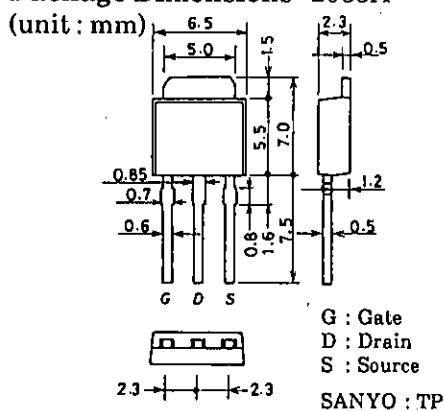
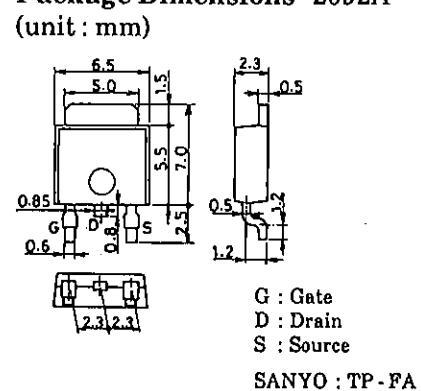
- Low ON resistance.
- Very high-speed switching.
- Low-voltage drive.

Absolute Maximum Ratings at Ta = 25°C

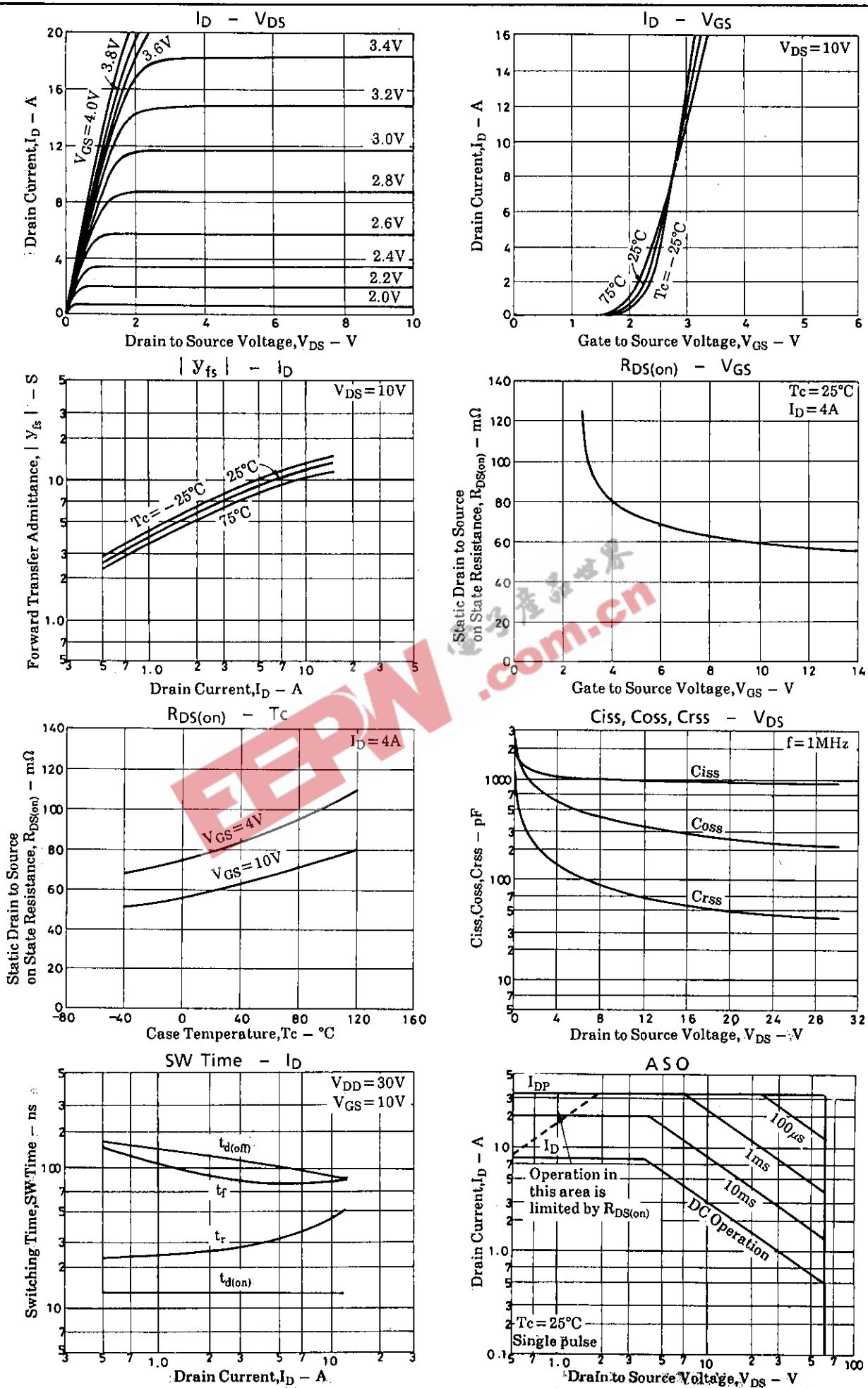
			unit
Drain to Source Voltage	V _{DSS}	60	V
Gate to Source Voltage	V _{GSS}	±15	V
Drain Current(DC)	I _D	8	A
Drain Current(Pulse)	I _{DP}	32	A
Allowable Power Dissipation	P _D	1.0	W
	T _c =25°C	30	W
Channel Temperature	T _{ch}	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

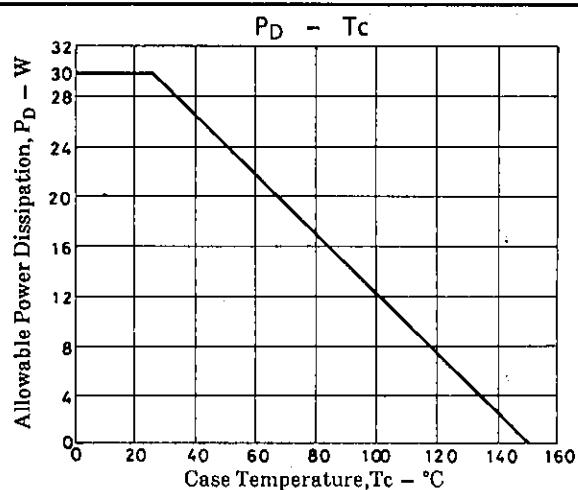
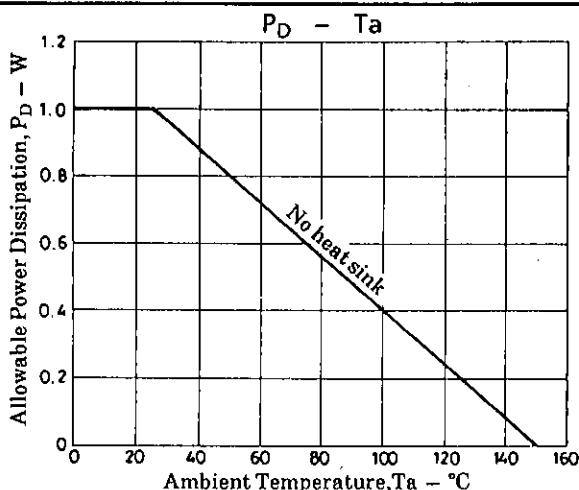
Electrical Characteristics at Ta = 25°C

			min	typ	max	unit
D-S Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0	60			V
G-S Breakdown Voltage	V _{(BR)GSS}	I _G =±100μA, V _{DS} =0	±15			V
Zero Gate Voltage	I _{DSS}	V _{DS} =60V, V _{GS} =0			100	μA
Drain Current						
Gate to Source Leakage Current	I _{GSS}	V _{GS} =±12V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	1.0		2.0	V
Forward Transfer Admittance	Y _{fs}	V _{DS} =10V, I _D =4A	5	8		S
Static Drain to Source	R _{DS(on)}	I _D =4A, V _{GS} =10V	60	80		mΩ
on State Resistance	R _{DS(on)}	I _D =4A, V _{GS} =4V	80	110		mΩ
Input Capacitance	C _{iss}	V _{DS} =20V, f=1MHz	950			pF
Output Capacitance	C _{oss}	V _{DS} =20V, f=1MHz	250			pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =20V, f=1MHz	50			pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.	13			ns
Rise Time	t _r	"	30			ns
Turn-OFF Delay Time	t _{d(off)}	"	110			ns
Fall Time	t _f	"	80			ns
Diode Forward Voltage	V _{SD}	I _S =8A, V _{GS} =0	1.0	1.5		V

Switching Time Test Circuit**Package Dimensions 2083A****Package Dimensions 2092A**

SANYO Electric Co., Ltd. Semiconductor Business Headquarters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN





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